# Quad 2-input NAND Schmitt trigger BU4093B/BU4093BF/BU4093BFV

The BU4093B, BU4093BF, and BU4093BFV are 4-circuit, 2-input NAND gates whose input pins all have a Schmitt trigger function.

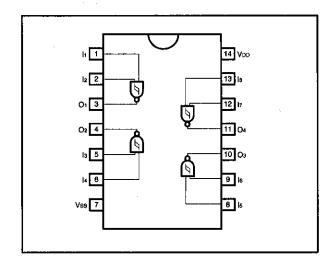
As the circuit threshold voltages are different when the input waveform rises and when it falls  $(V_{IH}, V_{IL})$ , they can be used for line receivers, waveform rectification, multivibrators, and other purposes in addition to the customary usage as a NAND gate. They may be used in place of the BU4011B which uses the same pin connection.

#### Features

- 1) Low power consumption.
- 2) Wide range of operating supply voltages.
- 3) High input impedance.

- 4) High fan-out.
- 5) Direct drive of 2 L-TTL inputs and 1 LS-TTL input.

#### Block diagram



#### ●Truth table

| INF | OUTPUT |        |
|-----|--------|--------|
| Α   | В      | COTFOT |
| L   | L      | Н      |
| L   | Н      | Н      |
| Н   | L      | Н      |
| Н   | Н      | L      |

BU4000B series

## ●Absolute maximum ratings (Ta=25℃)

| Parameter             | Symbol          | Limits                              | Unit |
|-----------------------|-----------------|-------------------------------------|------|
| Power supply voltage  | V <sub>DD</sub> | -0.3~18                             | ٧    |
| Power dissipation     | Pd              | 1000 (DIP) , 450 (SOP) , 350 (SSOP) | mW   |
| Operating temperature | Topr            | -40~85                              | °C   |
| Storage temperature   | Tstg            | <b>−55~150</b>                      | ొ    |
| Input voltage         | Vin             | -0.3~Vpp+0.3                        | ٧    |

#### Electrical characteristics

DC characteristics (unless otherwise noted, Ta=25°C)

| Parameter Sym                |                     | Min.  | Тур. | Max. | Unit |            | Conditions          | Measurement<br>Circuit |
|------------------------------|---------------------|-------|------|------|------|------------|---------------------|------------------------|
| - aramoter Symbol            | V <sub>DD</sub> (V) |       |      |      |      | Conditions |                     |                        |
|                              |                     | 3.5   |      | _    | v    | 5          | _                   | Fig.1                  |
| "H" input voltage            | ViH                 | 7.0   | _    | _    |      | 10         |                     |                        |
|                              |                     | 11.0  | _    | -    |      | 15         | ]                   |                        |
|                              |                     | _     | _    | 1.5  | v    | 5          |                     | Fig.1                  |
| "L" input voltage            | Vı∟                 |       | _    | 3.0  |      | 10         | _                   |                        |
| _                            | ,                   |       | _    | 4.0  |      | 15         |                     |                        |
| "H" input current            | lın                 | _     | _    | 0.3  | μA   | 15         | V⊪=15V              | Fig.1                  |
| "L" input current            | lıL                 | _     |      | -0.3 | μA   | 15         | VIL=0V              | Fig.1                  |
|                              |                     | 4.95  | _    | _    |      | 5          | lo=0mA              | Fig.1                  |
| "H" output voltage           | Vон                 | 9.95  | -    | _    | V    | 10         |                     |                        |
|                              |                     | 14.95 | _    |      |      | 15         |                     |                        |
|                              |                     | -     | _    | 0.05 | V    | 5          | to=0mA              | Fig.1                  |
| "L" output voltage           | Vol                 | _     | _    | 0.05 |      | 10         |                     |                        |
|                              |                     |       | _    | 0.05 |      | 15         |                     |                        |
|                              |                     | -0.16 | _    | _    |      | 5          | VoH=4.6V            | Fig.1                  |
| "H" output current           | Юн                  | -0.4  |      | _    | mA   | 10         | Vон=9.5V            |                        |
|                              |                     | -1.2  | _    | _    |      | 15         | Vон≕13.5V           |                        |
|                              |                     | 0.44  |      | -    | mA   | 5          | VoL=0.4V            | Fig.1                  |
| "L" output current           | lor                 | 1.1   |      | _    |      | 10         | Vol=0.5V            |                        |
|                              |                     | 3.0   | _    | _    | l.   | 15         | VoL=1.5V            |                        |
| Quiescent IDD Supply current |                     | _     |      | 1    | μА   | 5          | V₁=Vɒɒ or GND Fig.1 | Fig.1                  |
|                              | loo                 | _     |      | 2    |      | 10         |                     |                        |
|                              |                     |       | _    | 4    |      | 15         |                     |                        |
|                              |                     | 0.17  | _    | 0.39 | V    | 5          |                     | Fig.3                  |
| Hysteresis voltage           | Vн                  | 0.25  |      | 0.60 |      | 10         | - Fig.S             |                        |
|                              |                     | 0.33  | -    | 0.90 |      | 15         |                     |                        |

#### Electrical characteristics

Switching characteristics (unless otherwise noted, Ta=25℃, CL=50pF)

| Parameter   | Symbol                | Min. | Тур. | Max. | Unit. | V <sub>DD</sub> (V) | Conditions     | Measurement<br>Circuit |
|---|-----------------------|------|------|------|-------|---------------------|----------------|------------------------|
|   |                       | _    | 100  | -    |       | 5                   |                | Fig.2                  |
| Output rise time  | <b>t</b> TLH          | _    | 50   |      | ns .  | 10                  | ·              |                        |
|   |                       | _    | 40   | _    | ]     | 15                  |                |                        |
| -   |                       | -    | 100  |      |       | 5                   | <del>-</del> . | Fig.2                  |
| Output fall time  | Output fall time trhL |      | 50   | _    | ns    | 10                  |                |                        |
|   |                       | _    | 40   | _    |       | 15                  |                |                        |
| Propagation delay   |                       |      | 125  | _    | ns    | 5                   | —              | Fig.2                  |
| time, "L" to "H"  | <b>t</b> PLH          |      | 50   | _    |       | 10                  |                |                        |
| une, L to H   |                       |      | 40   | _    |       | 15                  |                |                        |
| Daniel de la constitución de la |                       |      | 125  |      | ns    | 5                   | _              | Fig.2                  |
| Propagation delay tehl.   | t <sub>РН</sub> .     | _    | 50   | _    |       | 10                  |                |                        |
|   |                       | _    | 40   |      |       | 15                  |                |                        |
| Input capacitance   | Cin                   |      | 5    |      | pF    |                     | <u> </u>       |                        |

#### Measurement circuits

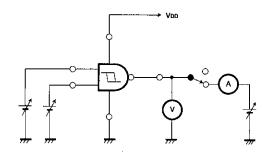


Fig. 1 DC characteristics measurement circuit

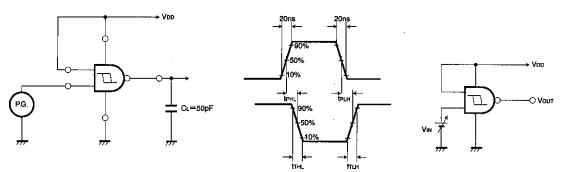


Fig. 2 Switching characteristic measurement circuit

Fig. 3 Hysteresis voltage measurement circuit





CMOS logic

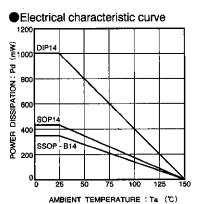
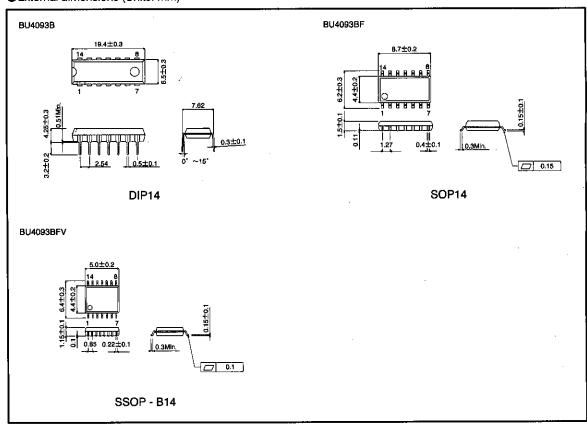


Fig. 4 Power dissipation - Ta characteristic

### External dimensions (Units: mm)



# Series Standard **BU4000B**

The BU4000 Series are CMOS ICs featuring low voltage and low power consumption. The wide range of operating power supply voltages is compatible with the general-purpose 4000B Series, and when a 5V power supply voltage is used, the LS-TTL IC can be driven directly.

These ICs are available in SOP and SSOP packages as well as the standard DIP package.

1) Low power consumption.

- 4) High fan-out.
- 2) Wide range of operating power supply voltages.
- 5) Direct drive of 2 L-TTL inputs and 1 LS-TTL input.

3) High input impedance.

#### ●Absolute maximum ratings (Ta = 25°C)

| Parameter            | Symbol      | Limits  | Unit |
|----------------------|-------------|---|------|
| Power supply voltage | <b>V</b> DD | 18 *1   | ٧    |
| Input voltage        | Vin         | -0.3~Vpp+0.3  | ٧    |
| Power dissipation *2 | Pd          | Please refer to specifications for individual package | mW   |
| Storage temperature  | Tstg        | 55~150  | ొ    |

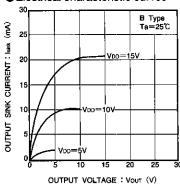
<sup>\*1</sup> For the BU4XXXBC type, Vpp = 20 V.

#### ■Recommended operating conditions (Ta = 25℃)

| Parameter             | Symbol | Limits        | Unit |
|-----------------------|--------|---------------|------|
| Power supply voltage  | Voo    | 3~16*         | V    |
| Input voltage         | Vin    | 0~Vpp         | V    |
| Operating temperature | Topr   | <b>−40~85</b> | ౮    |

<sup>\*</sup> For the BU4XXXBC type, Vpp = 3 to 18 V.

#### Electrical characteristic curves



voltage characteristic

Fig.2 Output source current - output Fig.1 Output sink current - output voltage characteristic

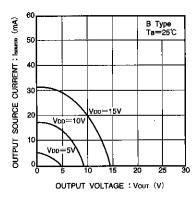
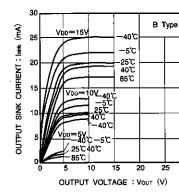


Fig.3 Output SINK current - output



voltage characteristic

<sup>\*2</sup> The values for the SOP and SSOP packages are the values when mounted on a glass epoxy PCB (50 mm x 50 mm x 1.6 mm).

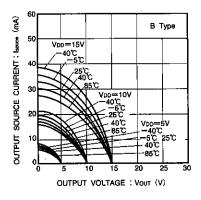


Fig.4 Output source current - output voltage characteristic

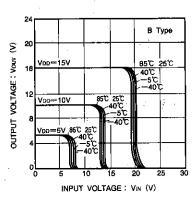
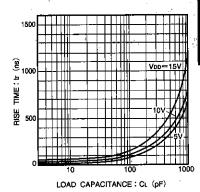
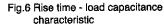


Fig.5 Output voltage - input voltage characteristic



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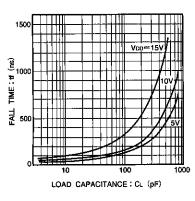


Fig.7 Fall time - load capacitance characteristic

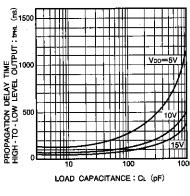


Fig.8 "H" to "L" propagation delay time - load capacitance characteristic

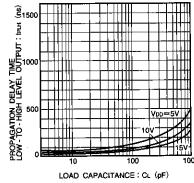


Fig.9 "L" to "H" propagation delay time load capacitance characteristic

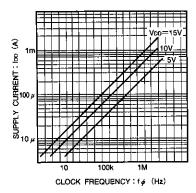


Fig.10 Supply current - clock frequency characteristic

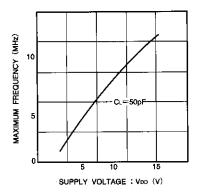


Fig.11 Maximum clock frequency - power supply voltage characteristic

**BU4000B** series

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